

ECN3063

ECN3063 is monolithic IC integrating 6 IGBTs.

It can be applied to DC brushless motors.

Functions

- * Integrated charge pump circuit
- * Free Wheeling Diodes are integrated
- * Overcurrent Protection circuit is integrated

Features

- * PWM control of upper and bottom arm IGBTs are possible by controlling outer Microprocessor
- * 6 Logic inputs are compatible with 5V CMOS or LSTTL outputs
- * Upper and Bottom arm IGBTs can operate in 20kHz chopping frequency
- * For converted AC200 to 230V power supplies

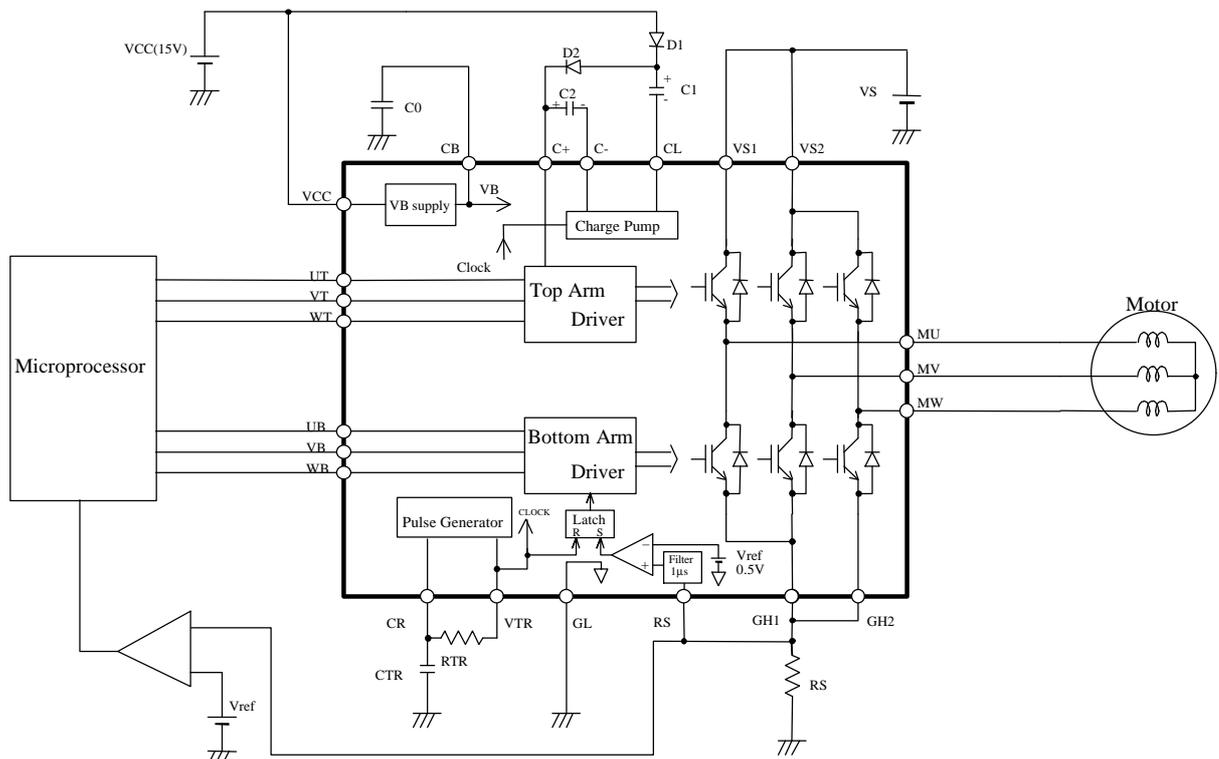


Fig.1 Block Diagram

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ECN3063

1. General

- (1) Type ECN3063SP,ECN3063SPV,ECN3063SPR
- (2) Application 3-Phase DC Brushless Motor
- (3) Structure Monolithic IC
- (4) Package SP-23TA,SP-23TB,SP23-TR

2. Maximum Allowable Ratings (Ta=25°C)

No.	Items	Symbols	Terminal	Ratings	Unit	Condition
1	Output Device Breakdown Voltage	VSM	VS1,VS2 MU,MV,MW	500	V	
2	Supply Voltage	VCC	VCC	18	V	
3	Input Voltage	VIN	UT,VT,WT, UB,VB,WB	-0.5 ~ VB+0.5	V	
4	Output Current	IMDC	MU,MV,MW	0.7	A	
5	Peak Output Current	IMP	MU,MV,MW	1.0	A	Note 1
6	Output Current in Start Up and Accelerating	IOM	MU,MV,MW	1.0	A	Note 1
7	Operating Junction Temperature	Tjop		-20 ~ +135	°C	Note 2
8	Storage Temperature	Tstg		-40 ~ +150	°C	

Note 1. Please note that accumulated duty of a period exceeding 0.7A has to be less than 5% of total current flowing period.

Note 2. Thermal Resistance

$$R_{j-c} = 4 \text{ } ^\circ\text{C/W}$$

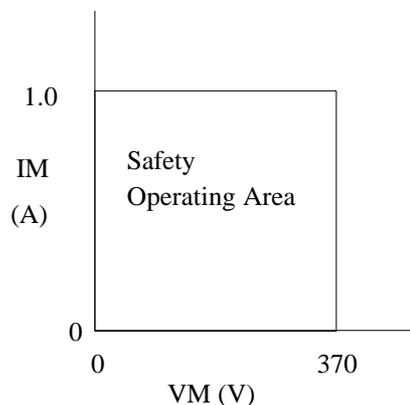
$$R_{j-a} = 40^\circ\text{C/W}$$

3. Recommended Operating Conditions

No.	Items	Symbols	Terminal	MIN	TYP	MAX	Unit	Condition
1	Supply Voltage	VS	VS1,2	50	325	370	V	
2		VCC	VCC	13.5	15	16.5	V	

Note 1. Recommended Area of Safety Operation

It is recommended that this IC is used within the SOA as shown below where IM and VM are the current and the voltage at the terminal of motor wiring at the change of phase (turn off).



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4. Electrical Characteristics (Ta=25°C)

Unless otherwise specified, VCC=15V, VS=325V

Suffix T; Top arm B; Bottom arm

No.	Items	Symbols	Terminal	MIN	TYP	MAX	Unit	Condition
1	Standby Current	IS	VS1,2	-	2.5	5.0	mA	UT,VT or WT=5V Other input=0V
2		ICC	VCC	-	10	20	mA	
3	Output device FVD	VFT	MU,MV,MW	-	4.0	6.0	V	I=0.35A
4		VFB	MU,MV,MW	-	4.0	6.0	V	
5	Turn On	TdONT	MU,MV,MW	-	0.5	2.0	μs	I=0.35A Resistance Load
6	Delay Time	TdONB	MU,MV,MW	-	0.5	2.0	μs	
7	Turn Off	TdOFFT	MU,MV,MW	-	1.0	2.0	μs	
8	Delay Time	TdOFFB	MU,MV,MW	-	1.0	2.0	μs	
9	Diode FVD	VFDT	MU,MV,MW	-	2.2	3.0	V	I=0.35A
10		VFDB	MU,MV,MW	-	2.2	3.0	V	
11	Input Voltage	VIH	UT,VT,WT,	3.5	-	-	V	
12		VIL	UB,VB,WB	-	-	1.5	V	
13	Input Current	IIL	UT,VT,WT, UB,VB,WB	-	-	100	μA	Input=5V Note 1 Pull Down Resistance
14	VB Output Voltage	VB	CB	6.8	7.5	8.2	V	
15	VB Output Current	IB	CB	25	-	-	mA	delta Vload=0.1V
16	Reference Voltage for Overcurrent	Vref	RS	0.45	0.5	0.55	V	
17	LVSD Output Voltage	LVSDON	VCC,MU,	10.0	11.5	12.9	V	Note.2
18	LVSD recover Voltage	LVSDOFF	MV,MW	10.1	12.0	13.0	V	
19	LVSD reset hysteresis	Vrh		0.1	0.5	0.9	V	

Note 1. Pull Down Resistance are typically 200 kΩ.

Note.2 LVSD: Low Voltage Shut Down

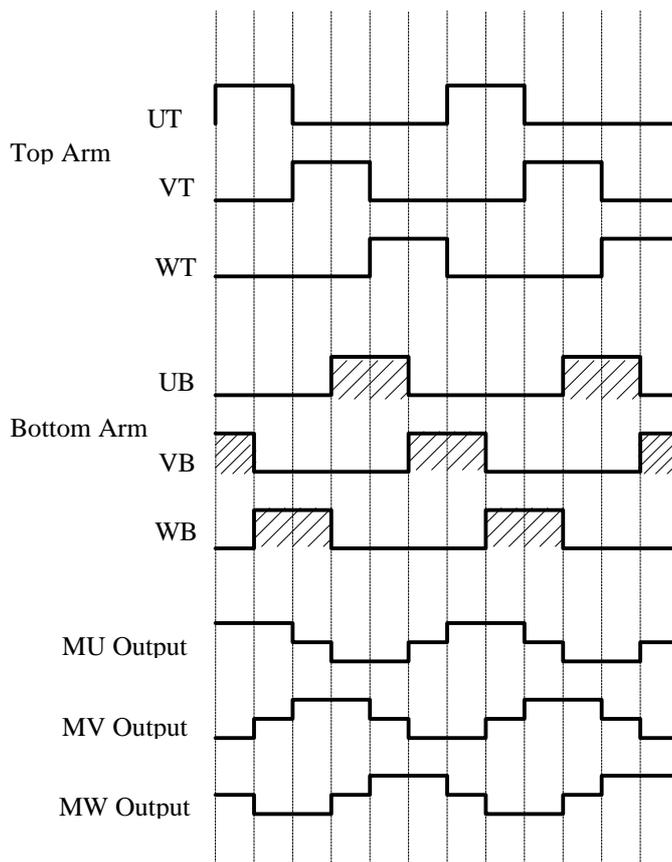
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5. Function

5.1 Truth Table

Terminal	Input	Output
UT,VT,WT, UB,VB,WB	L	OFF
	H	ON
UT,UB	UT&UB=H	OFF
VT,VB	VT&VB=H	OFF
WT,WB	WT&WB=H	OFF

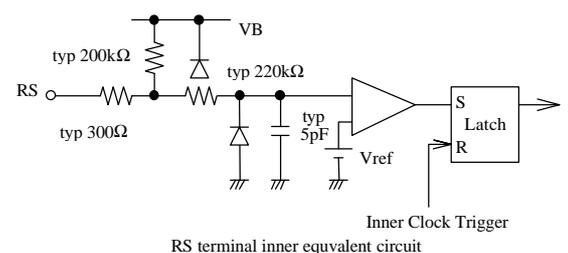
5.2 Timing Chart



5.3 Overcurrent Limiting Operation

This IC detects overcurrent by outside resistance R_s . When R_s input voltage exceeds inner reference voltage V_{ref} (0.5V typical), this IC turns off the bottom output. After overcurrent detection, a reset operation is done at each inner clock signal period.

In case of not using this function, please connect R_s terminal to GL terminal.



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6. Standard Application

Component	Recommended Value	Usage	Remark
C0	More than 0.22 μF	for inner power supply(VB).	stress voltage is VB
C1,C2	0.5 $\mu\text{F} \pm 20\%$	for charge pump	stress voltage is VCC
D1,D2	Hitachi DFG1C6 (glass mold) Hitachi DFM1F6(resin mold) or considerable parts	for charge pump	600V/1.0A trr \leq 100ns
CTR	1800 pF $\pm 5\%$	for clock	Note 1.
RTR	22 k $\Omega \pm 5\%$	for clock	Note 1.
Rs	Note.2	Overcurrent limit	

Note 1. Clock frequency is determined approximately by next equation.

Floating capacitance of PCB must be considered.

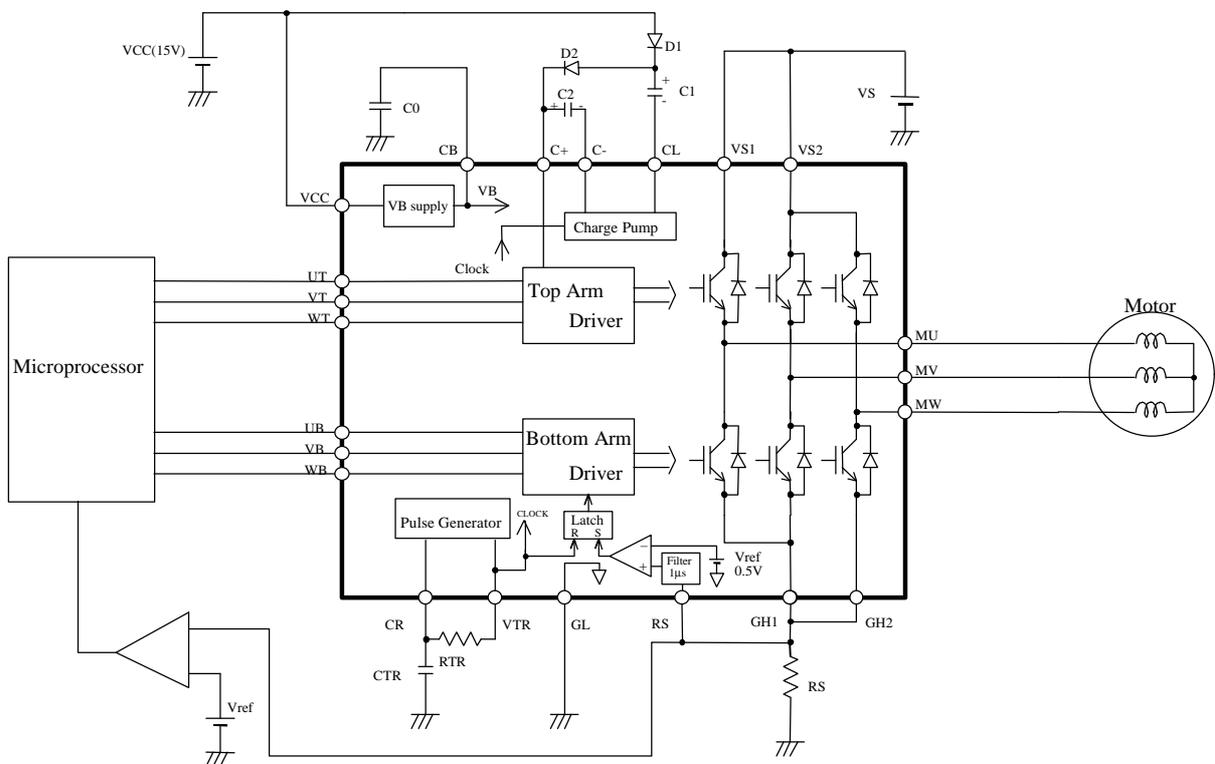
At Recommended Value of CR, the error factor of IC is about 10%.

$$f_{\text{clock}} = -1 / (2C * R * \text{Ln}(1 - 3.5/5.5)) \quad ; \text{Ln is natural logarithm}$$

$$= 0.494 / (C * R) \quad (\text{Hz})$$

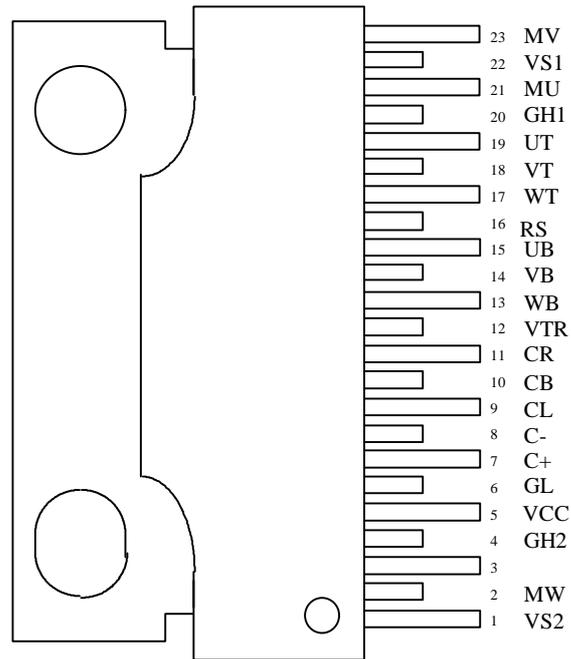
Note 2. Current is limited by the following equation.

$$I_O = V_{\text{ref}} / R_s \quad (\text{A})$$



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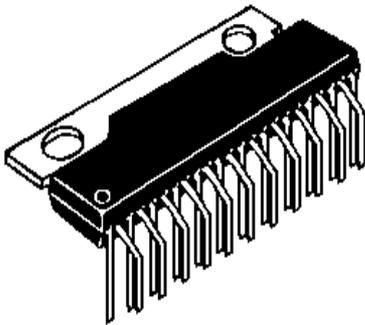
7. Terminal



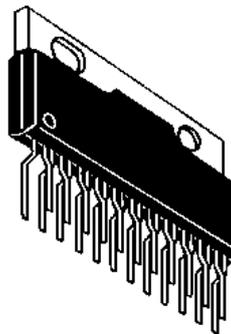
(Marking Side)

Fig.2 Pin Connection

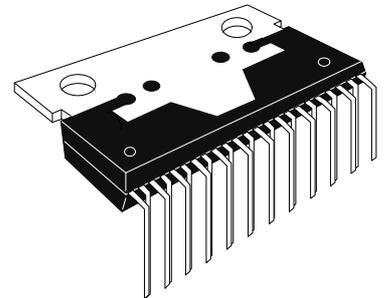
8. Package Outline



ECN3063SP
(SP-23TA)



ECN3063SPV
(SP-23TB)

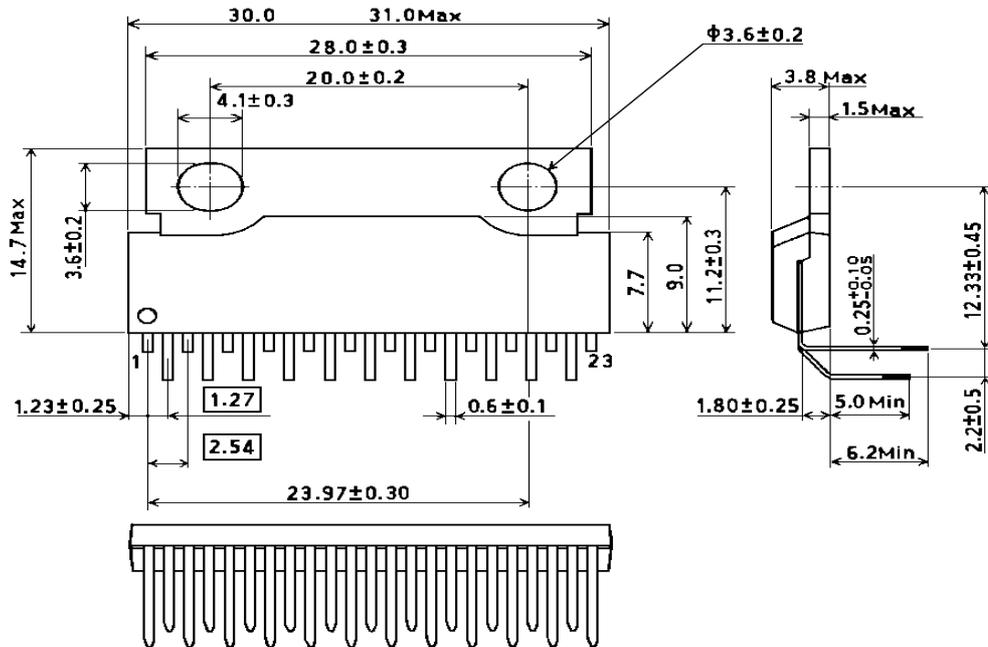


ECN3063SPR
(SP-23TR)

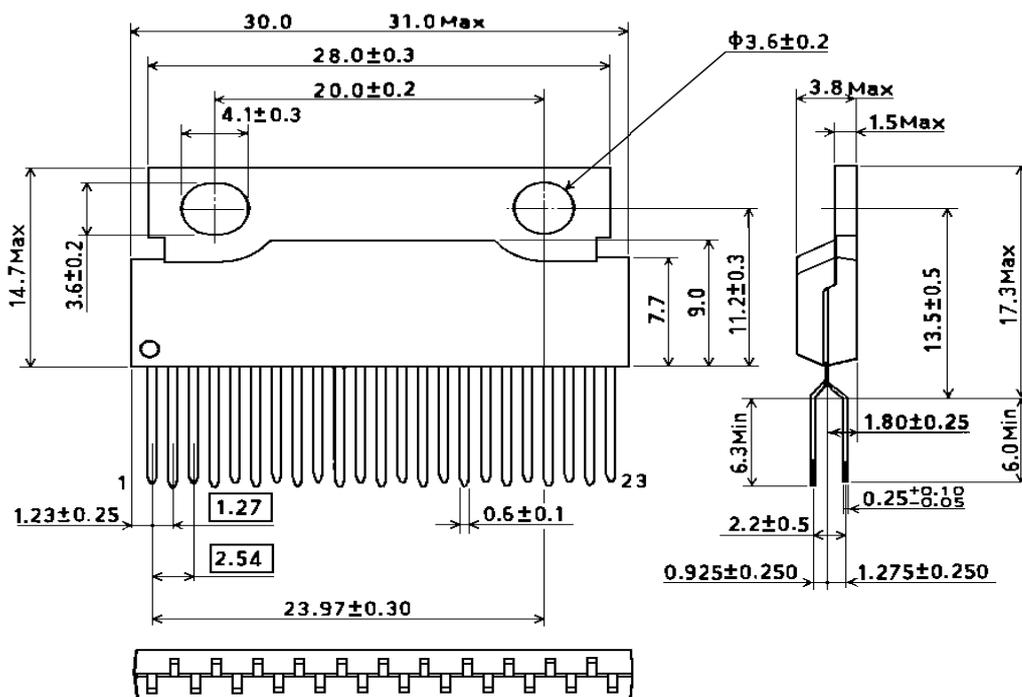
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8. Package Dimensions

(1) ECN3063SP



(2) ECN3063SPV



HITACHI POWER SEMICONDUCTORS

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